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CLAIMS:

- 1 1. A detector assembly for improved depth of interaction determinations comprising:
- a scintillator crystal for interacting with a photon and creating a plurality of
- 3 optical signals, said scintillator crystal having a first end and a second end;
- a first transducer for receiving one the plurality optical signals from said
- 5 scintillator crystal and converting the one the plurality optical signals to a first electrical
- 6 signal, said first transducer having a first active area for receiving optical signals, and
- 7 said first active area of said first transducer being optically coupled to the first end of said
- 8 scintillator crystal;
- a second transducer for receiving another of the plurality optical signals from said
- scintillator crystal and converting the one the plurality optical signals to a second
- electrical signal, said second transducer having a second active area for receiving optical
- signals and said second active area of said second transducer being optically aligned for
- 13 receiving optical signals from second end of said scintillator crystal; and
- an optical guide, said optical guide optically coupled between said second end of
- said scintillator crystal and said active area of said second transducer, said optical guide
- being conducive to direct optical signals to said active area of said second transducer.
- 1 2. The detector assembly recited in claim 1 above, wherein said first active area is
- 2 larger than said second active area.
- 1 3. The detector assembly recited in claim 1 above, wherein said scintillator crystal
- 2 further comprising:
- a plurality of slits, each of said plurality of slits being approximately equal in
- 4 length.

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- 1 4. The detector assembly recited in claim 1 above, wherein said second transducer is
- 2 one of a photodiode and further comprises:
- a semiconducting material, said semiconducting material having a low photon
- 4 absorption rate and a low photon scattering rate.
- 1 5. The detector assembly recited in claim 4 above, wherein said second transducer is
- 2 one of a photodiode and an avalanche photodiode (APD).
- 1 6. The detector assembly recited in claim 4 above, wherein said second transducer is
- an avalanche photodiode (APD).
- 1 7. The detector assembly recited in claim 5 above, wherein said first transducer is a
- 2 photomultiplier (PMT).
- 1 8. The detector assembly recited in claim 1 above further comprises:
- a third transducer for receiving one of the plurality of optical signals from said
- 3 scintillator crystal and converting the one of the plurality of optical signals to a third
- 4 electrical signal, said third transducer having a third active area for receiving optical
- 5 signals, and said third active area of said first transducer being optically coupled to the
- 6 first end of said scintillator crystal.
- 1 9. The detector assembly recited in claim 5 above, wherein said first and third
- 2 transducers are photomultipliers (PMT) and said second transducer is an avalanche
- **3** photodiode (APD).
- 1 10. The detector assembly recited in claim 9 above, wherein said scintillator crystal
- 2 being optically coupled between a plurality of optical guides and a plurality of
- **3** photomultipliers (PMT).

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- 1 11. The detector assembly above in claim 1 recited, wherein said first electrical signal
- 2 is related to a first distance from the first active area of the first transducer and an
- interaction point where said photon interacted with said scintillator crystal.
- 1 12. The detector assembly recited in claim 11 above, wherein said second electrical
- 2 signal is related to a second distance from the second active area of the second transducer
- 3 and the interaction point.
- 1 13. The detector assembly recited in claims 12 above, wherein a depth of interaction
- 2 (DOI) for the photon in said scintillator crystal is determined from said first electrical
- 3 signal, said second electrical signal and a distance between said first and second ends.
- 1 14. The detector assembly recited in claim 1 above, wherein said scintillator crystal
- 2 further comprises:
- a bismuth germanate (BGO) crystal.
- 1 15. The detector assembly recited in claim 1 above, wherein said scintillator crystal
- 2 further comprises:
- a plurality of bismuth germanate (BGO) crystals.
- 1 16. The detector assembly recited in claim 1 above, wherein said scintillator crystal
- **2** further comprises:
- a sodium iodate (NaI) crystal.
- 1 17. The detector assembly above in claim 1 recited, wherein said scintillator crystal
- 2 further comprises:
- a plurality of sodium iodate (NaI) crystals.

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- 1 18. The detector assembly above in claim 1 recited, wherein a distance between said
- 2 first and second ends exposes an oblique angle to a photon.